

## General Description

The AH9248 is an ultra-sensitive Hall-effect switch with digital latched output, mainly designed for battery-operation, hand-held equipments.

Special CMOS process is used for low-voltage and low-power requirement. A chopper stabilized amplifier improves stability of magnetic switch points. A sleep-awake logic controls the IC in sleep time or awake time. This function will reduce the average operating current of the IC. During the awake time, the output is changed with the magnetic flux density. During the sleep time, the output is latched in its previous state and the current consumption will reduce to some  $\mu\text{A}$ .

The IC switching behaviour is omnipolar, either north or south pole sufficient strength will turn the output on. If the magnetic flux density is larger than operating point ( $B_{OP}$ ), the output will be turned on; if it is less than releasing point ( $B_{RP}$ ), the output will be turned off.

The AH9248 is available in TO-92S-3, SOT-23-3 and DFN-2 $\times$ 2-3 packages which are optimized for most applications.

## Features

- Micropower Operation
- 2.5 to 5.5V Power Supply
- Switching for Both Poles of a Magnet (Omnipolar)
- Stabilized Chopper
- Superior Temperature Stability
- Digital Output Signal
- Built-in Pull-up Resistor (AH9249)

## Applications

- Cover Switch in Notebook PC/PDA
- Handheld Wireless Application Awake Switch
- Magnet Switch in Low Duty Cycle Applications

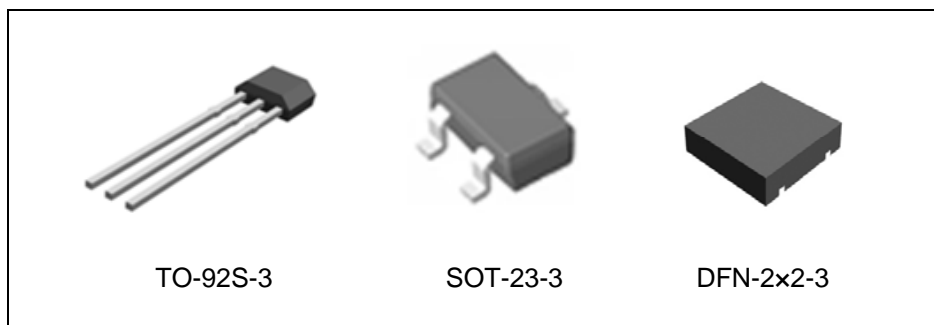


Figure 1. Package Types of AH9248

### Pin Configuration

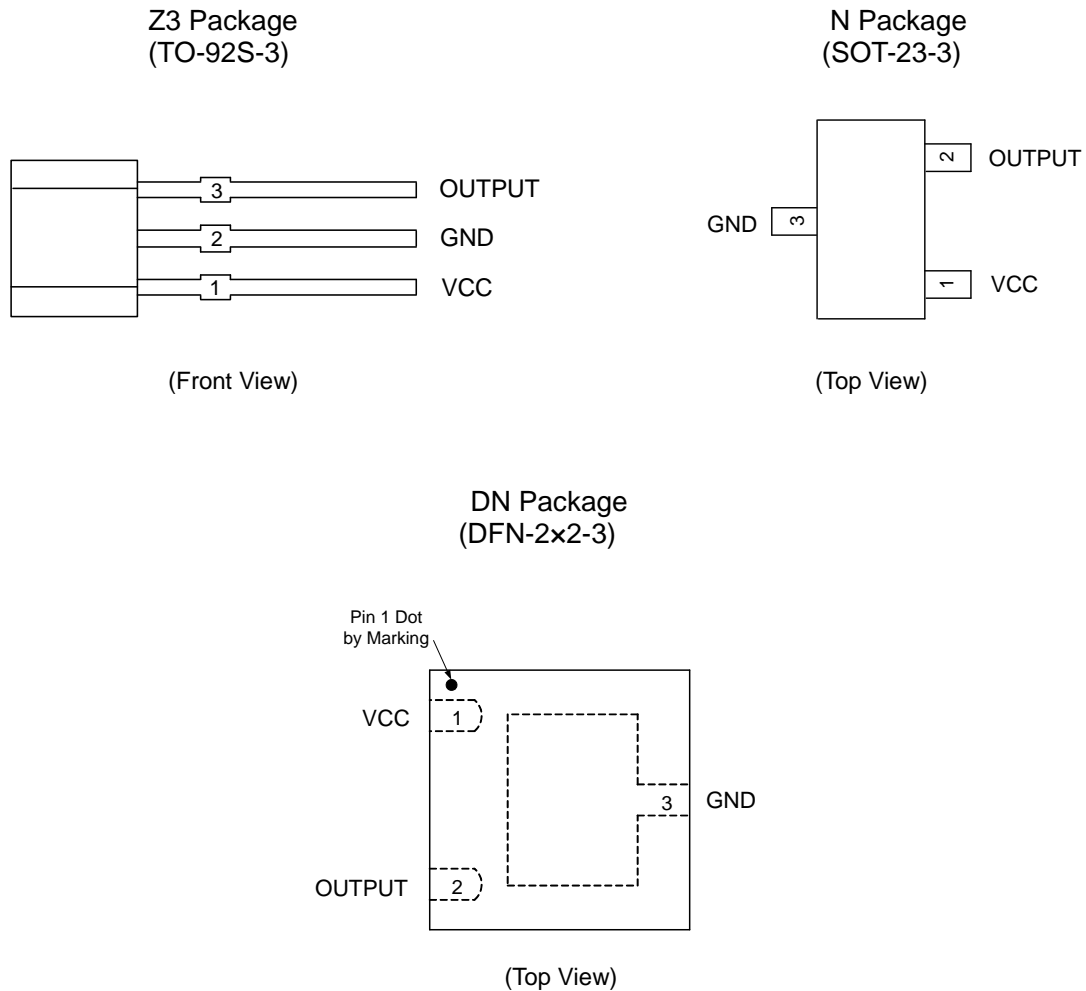
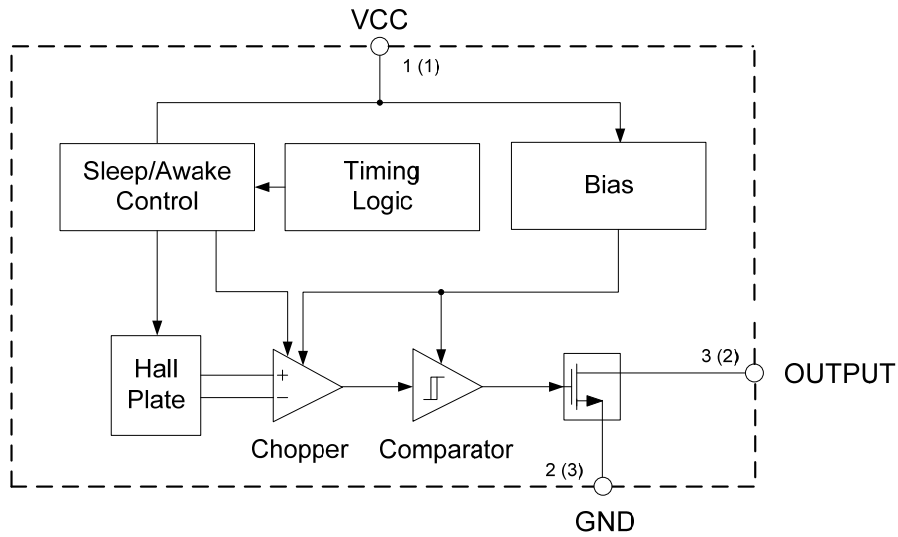


Figure 2. Pin Configuration of AH9248

### Pin Description

Pin Number			Pin Name	Function
TO-92S-3	SOT-23-3	DFN-2x2-3		
1	1	1	VCC	Power supply pin
2	3	3	GND	Ground pin
3	2	2	OUTPUT	Output pin

### Functional Block Diagram



A (B)  
 A for TO-92S-3  
 B for SOT-23-3 and DFN-2×2-3

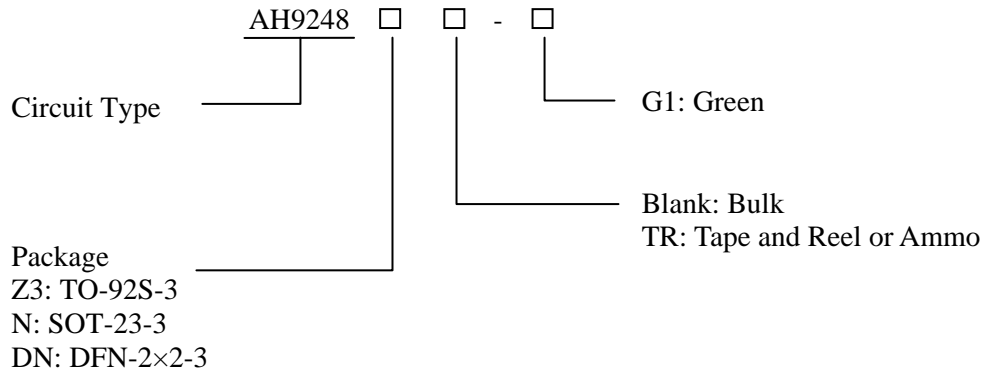
Figure 3. Functional Block Diagram of AH9248



High Sensitivity Micropower Omnipolar Hall-Effect Switch

AH9248

Ordering Information



Package	Temperature Range	Part Number	Marking ID	Packing Type
TO-92S-3	-40 to 85°C	AH9248Z3-G1	9248	Bulk
		AH9248Z3TR-G1	9248	Ammo
SOT-23-3		AH9248NTR-G1	GL1	Tape & Reel
DFN-2×2-3		AH9248DNTR-G1	JA	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "G1" suffix in the part number, are RoHS compliant and green.

**High Sensitivity Micropower Omnipolar Hall-Effect Switch****AH9248****Absolute Maximum Ratings (T<sub>A</sub>=25°C, Note 1)**

Parameter	Symbol	Value		Unit
Supply Voltage	V <sub>CC</sub>	7		V
Supply Current (Fault)	I <sub>CC</sub>	6		mA
Output Voltage	V <sub>OUT</sub>	7		V
Output Current	I <sub>OUT</sub>	2		mA
Magnetic Flux Density	B	Unlimited		Gauss
Power Dissipation	P <sub>D</sub>	TO-92S-3	400	mW
		SOT-23-3	230	
		DFN-2×2-3	230	
Storage Temperature	T <sub>STG</sub>	-55 to 150		°C
Junction Temperature	T <sub>J</sub>	150		°C
ESD (Machine Model) (Note 2)	ESD	200		V

Note 1: Stresses greater than those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “Recommended Operating Conditions” is not implied. Exposure to “Absolute Maximum Ratings” for extended periods may affect device reliability.

Note 2: Electronic semiconductor products are sensitive to Electro Static Discharge (ESD). Always observe Electro Static Discharge control procedures whenever handling semiconductor products.

**Recommended Operating Conditions**

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V <sub>CC</sub>	2.5	5.5	V
Operating Temperature	T <sub>OP</sub>	-40	85	°C

**High Sensitivity Micropower Omnipolar Hall-Effect Switch****AH9248****Electrical Characteristics** $V_{CC}=3V$ ,  $T_A=25^{\circ}C$ , unless otherwise specified.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Supply Voltage	$V_{CC}$	Operating	2.5	3	5.5	V
Supply Current	$I_{AW}$	Awake		2	4	mA
	$I_{SL}$	Sleep		6	10	$\mu A$
	$I_{AVG}$	Average		10	15	$\mu A$
Output Current	$I_{OUT}$				1.0	mA
Output Leakage Current	$I_{LEAK}$	$B <  B_{RP} $		<0.1	1	$\mu A$
Saturation Voltage	$V_{SAT}$	$I_{OUT}=1.0mA$			0.4	V
Awake Mode Time	$t_{AW}$	Operating		150		$\mu s$
Sleep Mode Time	$t_{SL}$	Operating		90	120	ms
Duty Cycle	D			0.15		%
Chopper Frequency	$f_C$			15		kHz

**Magnetic Characteristics (Note 3)** $V_{CC}=3V$ ,  $T_A=25^{\circ}C$ , unless otherwise specified.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Operating point	$B_{OPS}$	South pole to branded side $B > B_{OPS}, V_{OUT} = \text{low}(\text{output on})$		30	55	Gauss
	$B_{OPN}$	North pole to branded side $B > B_{OPN}, V_{OUT} = \text{low}(\text{output on})$	-55	-30		Gauss
Releasing Point	$B_{RPS}$	South pole to branded side $B < B_{RPS}, V_{OUT} = \text{high}(\text{output off})$	5	20		Gauss
	$B_{RPN}$	North pole to branded side $B < B_{RPN}, V_{OUT} = \text{high}(\text{output off})$		-20	-5	Gauss
Hysteresis	$B_{HYS}$	$ B_{OPX} - B_{RPX} $ (Note 4)		10		Gauss

Note 3: The specifications stated here are guaranteed by design. 1 Gauss=0.1mT

Note 4:  $B_{OPX}$ =operating point(output turns on);  $B_{RPX}$ =releasing point(output turns off)

Magnetic Characteristics (Continued)

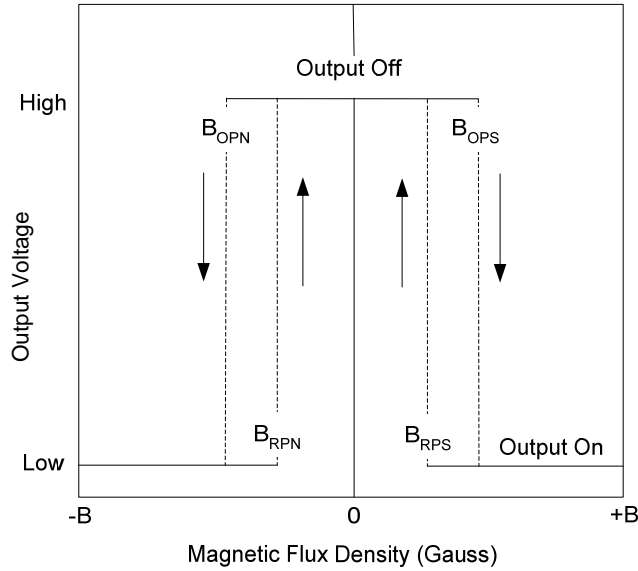


Figure 4. Output Voltage vs. Magnetic Flux Density

Test Conditions

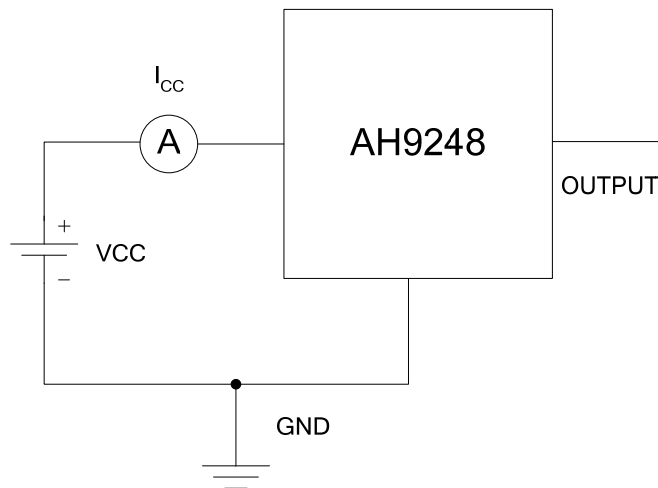


Figure 5. Average Supply Current (Note 5, 6)

Note 5:  $I_{CC}$  represents the average supply current. OUTPUT is open during measurement.

Note 6: The device is put under magnetic field with  $B < B_{RP}$ .

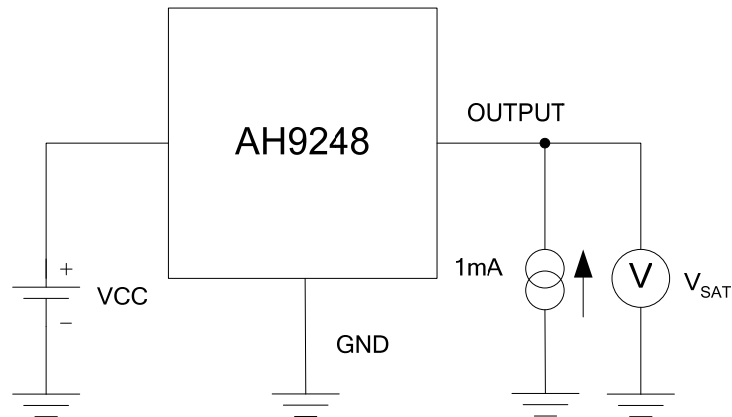
**Test Conditions (Continued)**


Figure 6. Output Saturation Voltage (Note 7, 8)

Note 7: The output saturation voltage  $V_{SAT}$  is measured at  $V_{CC}=2.5V$  and  $V_{CC}=5.5V$ .

Note 8: The device is put under magnetic field with  $B > B_{OP}$ .

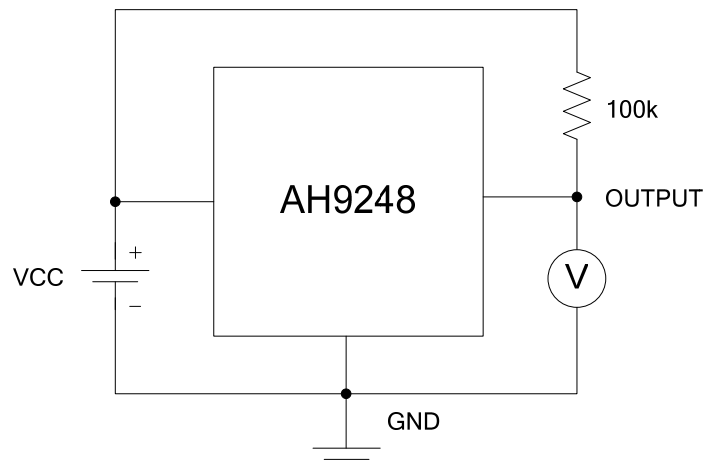


Figure 7. Magnetic Thresholds (Note 9, 10)

Note 9:  $B_{OP}$  is determined by putting the device under magnetic field swept from  $B_{RP(min)}$  to  $B_{OP(max)}$  until the output is switched on.

Note 10:  $B_{RP}$  is determined by putting the device under magnetic field swept from  $B_{OP(max)}$  to  $B_{RP(min)}$  until the output is switched off.



## Typical Performance Characteristics

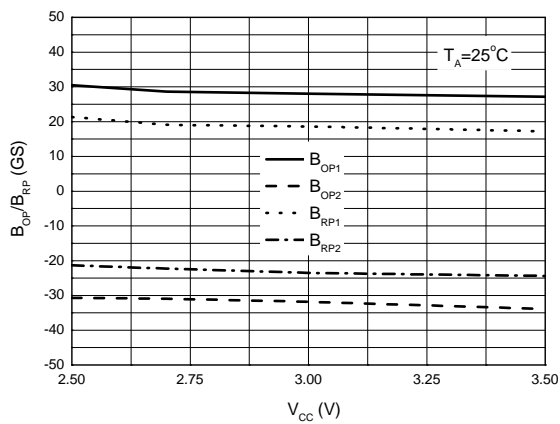
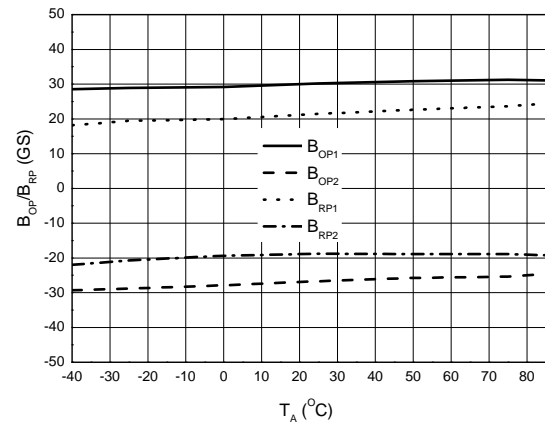
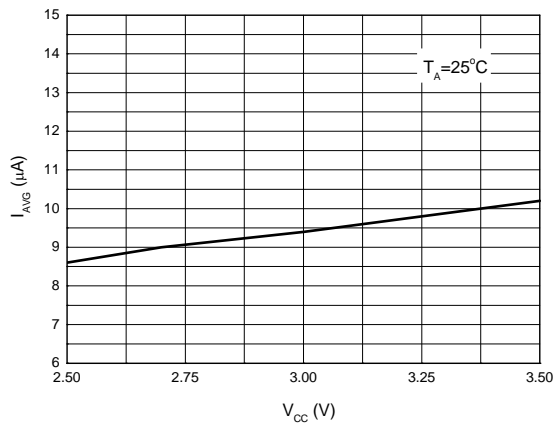

 Figure 8. B<sub>OP</sub>/B<sub>RP</sub> vs. Supply Voltage

 Figure 9. B<sub>OP</sub>/B<sub>RP</sub> vs. Ambient Temperature


Figure 10. Average Supply Current vs. Supply Voltage

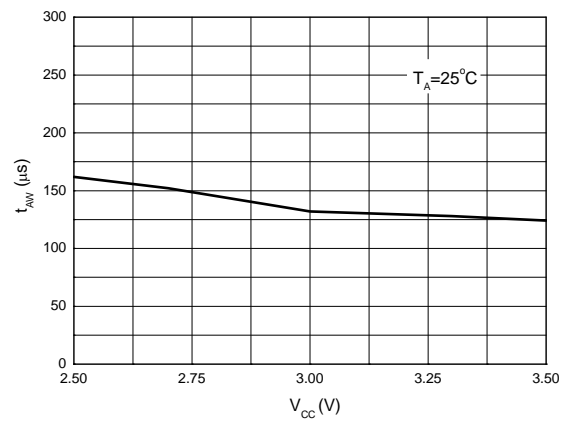


Figure 11. Awake Mode Time vs. Supply Voltage

Typical Performance Characteristics (Continued)

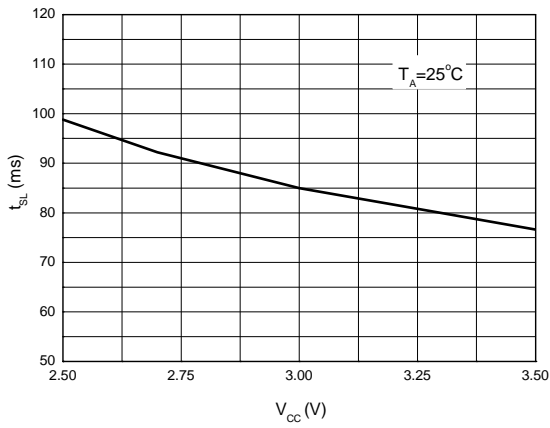


Figure 12. Sleep Mode Time vs. Supply Voltage

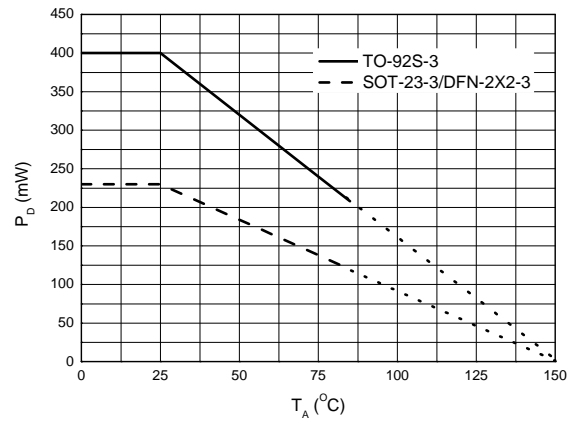


Figure 13. Power Dissipation vs. Ambient Temperature

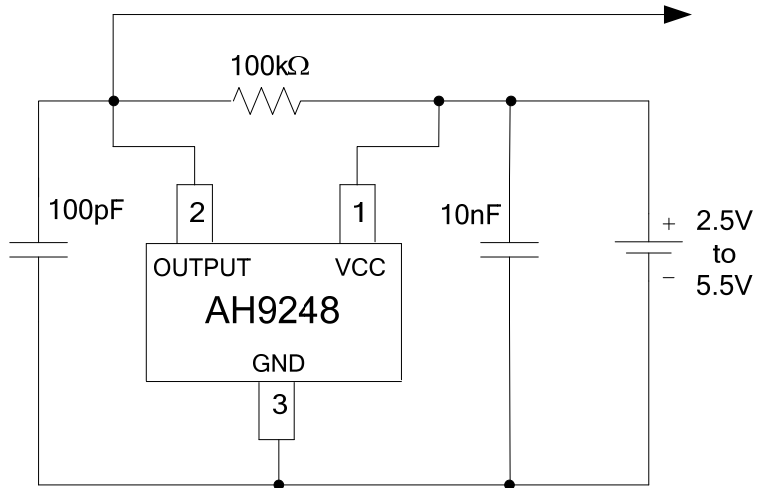
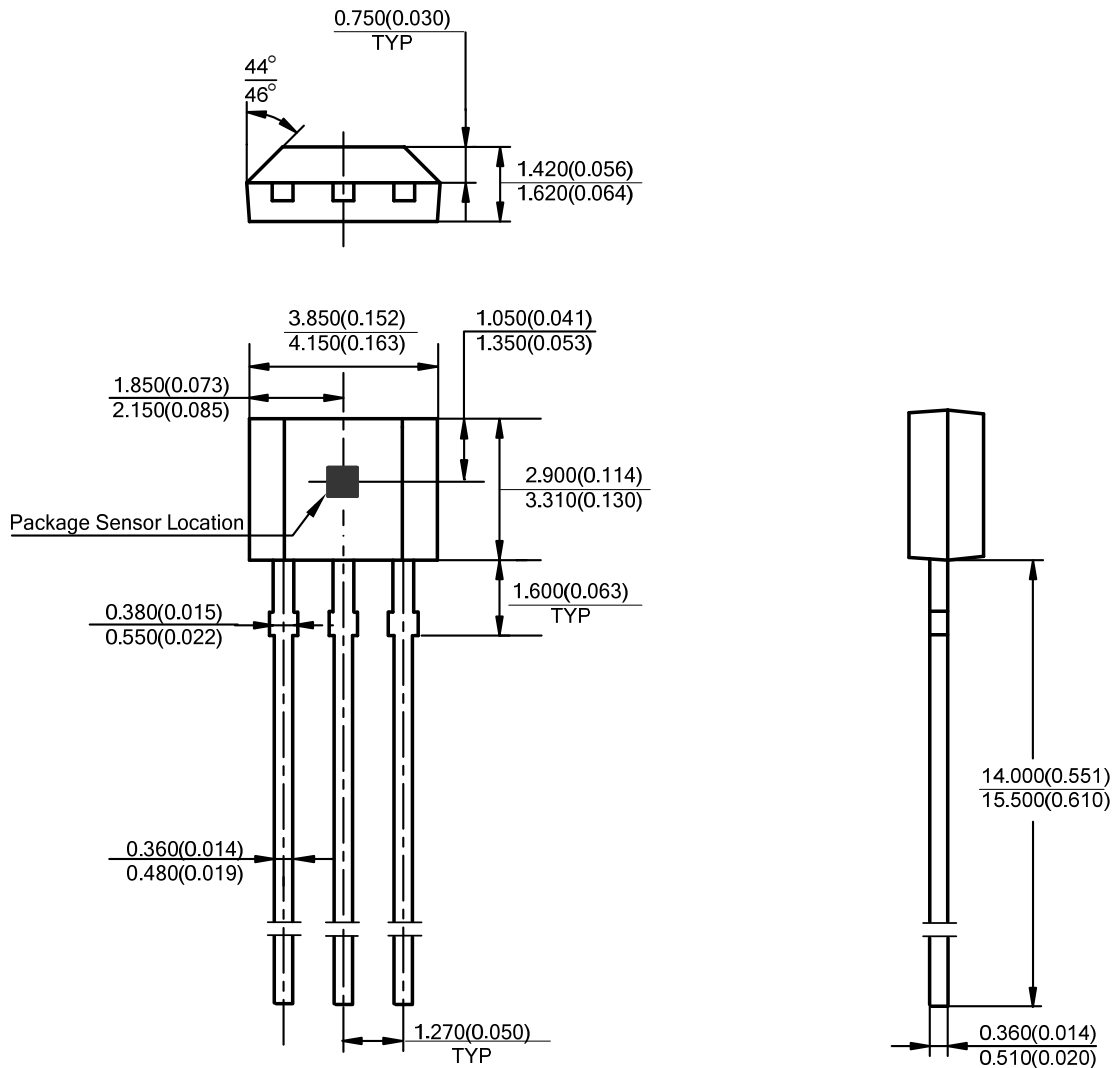
**Typical Application**

Figure 14. Typical Application of AH9248

Mechanical Dimensions

TO-92S-3

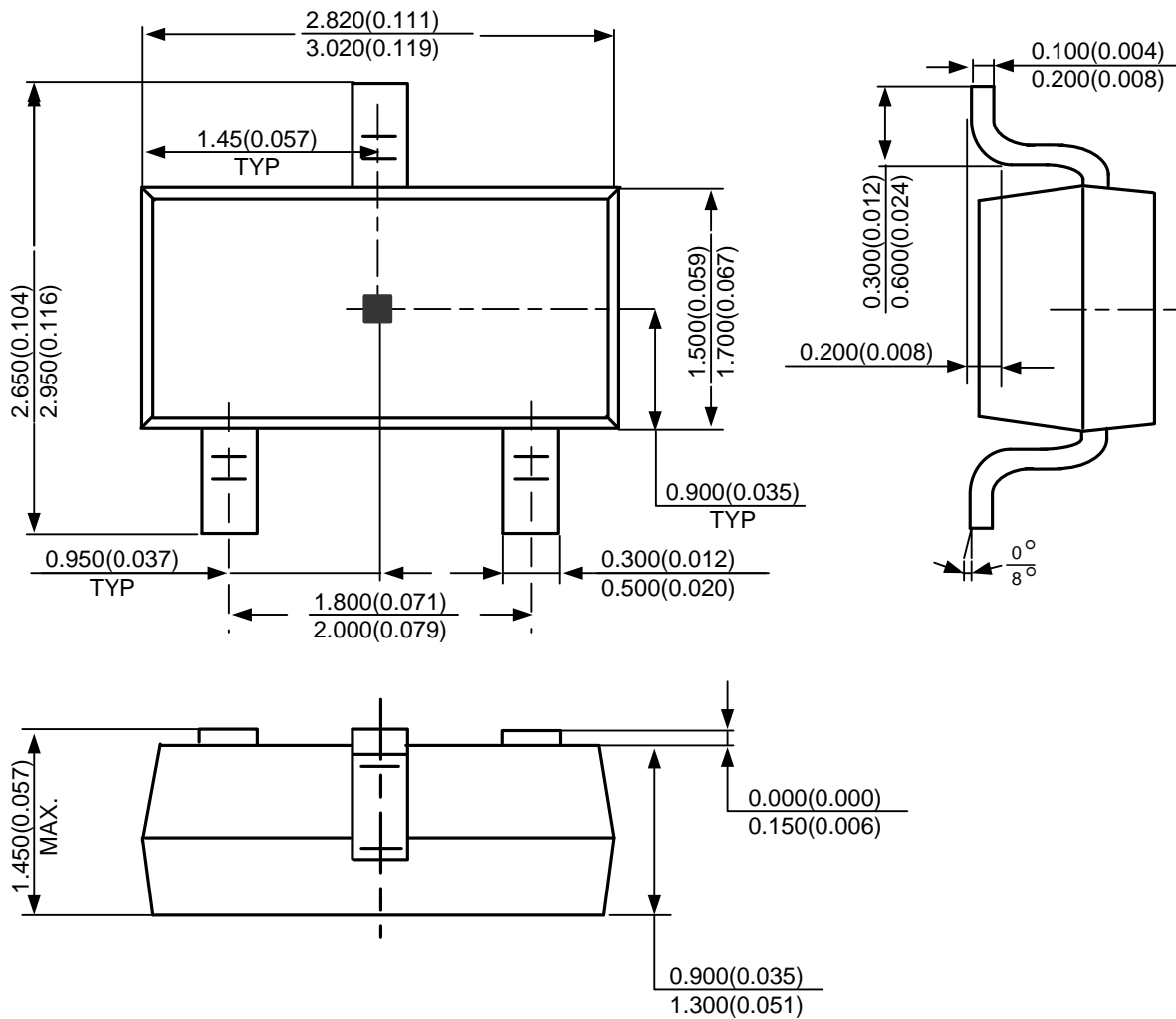
Unit: mm(inch)



Mechanical Dimensions (Continued)

SOT-23-3

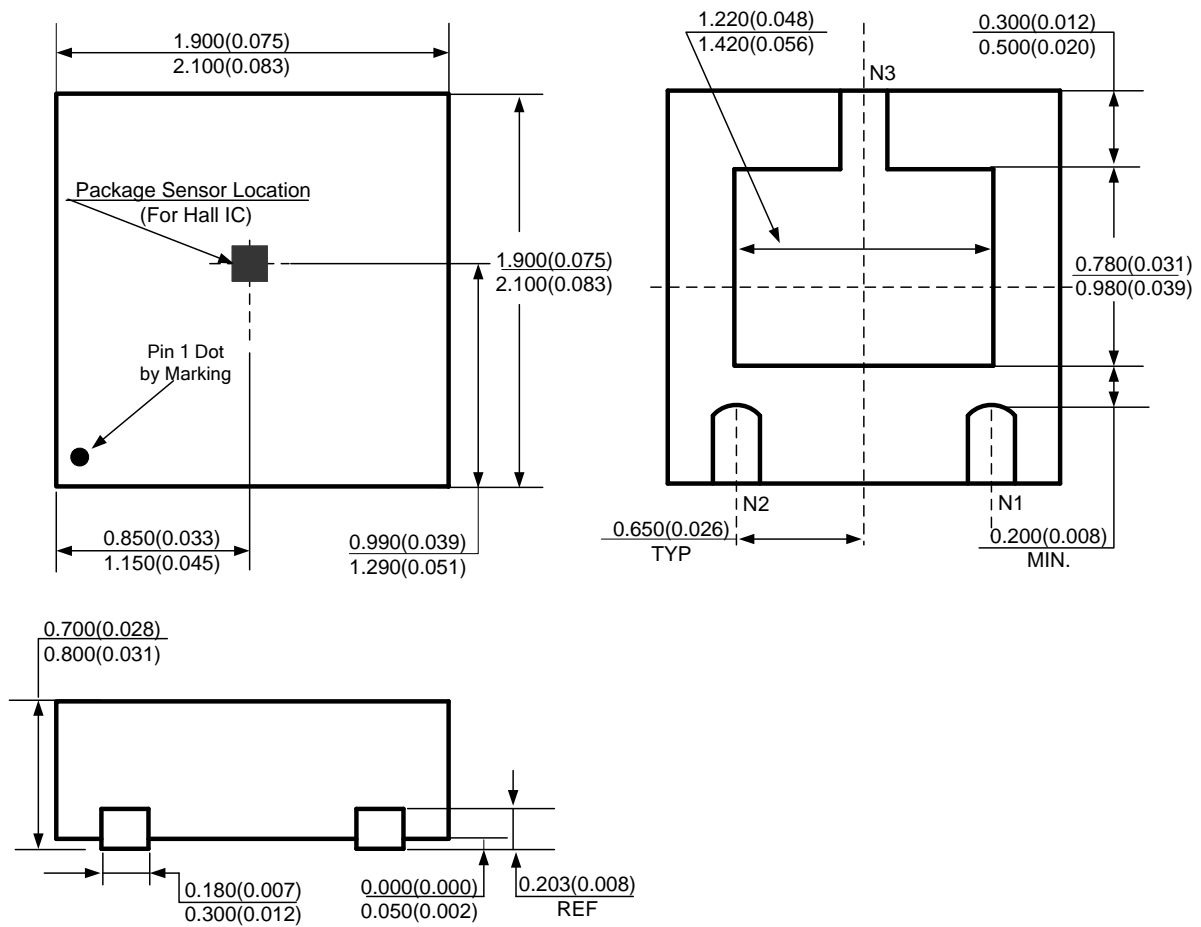
Unit: mm(inch)



Mechanical Dimensions (Continued)

DFN-2x2-3

Unit: mm(inch)





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#### **MAIN SITE**

##### **- Headquarters**

##### **BCD Semiconductor Manufacturing Limited**

No. 1600, Zi Xing Road, Shanghai Zizhu Science-based Industrial Park, 200241, China  
Tel: +86-21-24162266, Fax: +86-21-24162277

##### **- Wafer Fab**

##### **Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd.**

800 Yi Shan Road, Shanghai 200233, China  
Tel: +86-21-6485 1491, Fax: +86-21-5450 0008

#### **REGIONAL SALES OFFICE**

##### **Shenzhen Office**

##### **Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd., Shenzhen Office**

Unit A Room 1203, Skyworth Bldg., Gaoxin Ave. 1.S., Nanshan District, Shenzhen, China  
Tel: +86-755-8826 7951  
Fax: +86-755-8826 7865

##### **Taiwan Office**

##### **BCD Semiconductor (Taiwan) Company Limited**

4F, 298-1, Rui Guang Road, Nei-Hu District, Taipei, Taiwan  
Tel: +886-2-2656 2808  
Fax: +886-2-2656 2806

##### **USA Office**

##### **BCD Semiconductor Corp.**

30920 Huntwood Ave. Hayward, CA 94544, USA  
Tel : +1-510-324-2988  
Fax: +1-510-324-2788